## GD65232, GD75232 **MULTIPLE RS-232 DRIVERS AND RECEIVERS**

SLLS206J - MAY 1995 - REVISED NOVEMBER 2004

- Single Chip With Easy Interface Between UART and Serial-Port Connector of IBM™ **PC/AT** and Compatibles
- Meet or Exceed the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- **Designed to Support Data Rates up to** 120 kbit/s
- Pinout Compatible With SN75C185 and SN75185

#### description/ordering information

The GD65232 and GD75232 combine three drivers and five receivers from the Texas Instruments trade-standard SN75188 and **GD65232, GD75232...DB, DW, N, OR PW PACKAGE** (TOP VIEW) V<sub>DD</sub> [ ∐ ∨<sub>cc</sub> RA1 [] 2 19 🛮 RY1 RA2 🛮 3 18 ¶ RY2 RA3 **1**4 17 **∏** RY3 DY1 [] 5 16 **∏** DA1 DY2 **∏**6 15 ∏ DA2 RA4 **∏** 7 14 **∏** RY4 DY3 | 8 13 DA3 RA5 **∏** 9 12 **∏** RY5 V<sub>SS</sub> [] 10 11 **∏** GND

SN75189 bipolar guadruple drivers and receivers, respectively. The pinout matches the flow-through design of the SN75C185 to decrease the part count, reduce the board space required, and allow easy interconnection of the UART and serial-port connector of an IBM™ PC/AT and compatibles. The bipolar circuits and processing of the GD65232 and GD75232 provide a rugged, low-cost solution for this function at the expense of quiescent power and external passive components relative to the SN75C185.

The GD65232 and GD75232 comply with the requirements of the TIA/EIA-232-F and ITU (formerly CCITT) V.28 standards. These standards are for data interchange between a host computer and a peripheral at signaling rates up to 20 kbit/s. The switching speeds of these devices are fast enough to support rates up to 120 kbit/s with lower capacitive loads (shorter cables). Interoperability at the higher signaling rates cannot be expected unless the designer has design control of the cable and the interface circuits at both ends. For interoperability at signaling rates up to 120 kbit/s, use of TIA/EIA-423-B (ITU V.10) and TIA/EIA-422-B (ITU V.11) standards is recommended.

#### ORDERING INFORMATION

TA	PACKA	GE <sup>†</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP (N)	Tube of 20	GD65232N	GD65232N
	0010 (DIA)	Tube of 25	GD65232DW	000000
4000 1- 0500	SOIC (DW)	Reel of 2000	GD65232DWR	GD65232
-40°C to 85°C	SSOP (DB)	Reel of 2000	GD65232DBR	GD65232
	T000D (DW)	Tube of 70	GD65232PW	000000
	TSSOP (PW)	Reel of 2000	GD65232PWR	GD65232
	PDIP (N)	Tube of 20	GD75232N	GD75232N
	COIC (DIA)	Tube of 25	GD75232DW	OD75000
000 to 7000	SOIC (DW)	Reel of 2000	GD75232DWR	GD75232
0°C to 70°C	SSOP (DB)	Reel of 2000	GD75232DBR	GD75232
	TESOD (DW)	Tube of 70	GD75232PW	CD75222
	TSSOP (PW)	Reel of 2000	GD75232PWR	GD75232

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

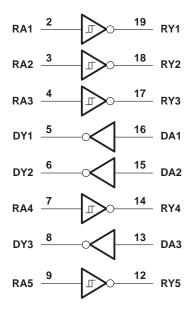


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

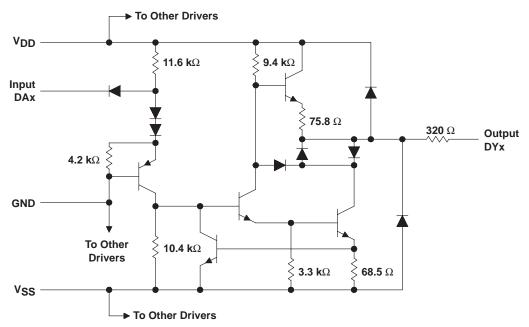
IBM is a trademark of International Business Machines Corporation.



#### logic diagram (positive logic)



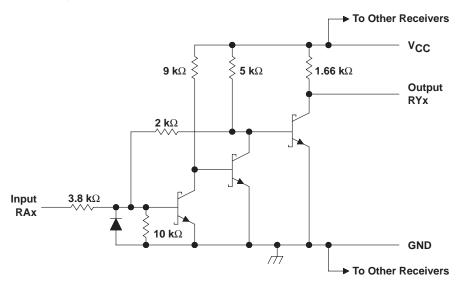
## schematic (each driver)



Resistor values shown are nominal.



#### schematic (each receiver)



Resistor values shown are nominal.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage (see Note 1): V <sub>CC</sub>	10 V
	15 V
V <sub>SS</sub>	
Input voltage range, V <sub>I</sub> : Driver	–15 V to 7 V
Receiver	–30 V to 30 V
Driver output voltage range, VO	
Receiver low-level output current, I <sub>OL</sub>	20 mA
Package thermal impedance, $\theta_{JA}$ (see Notes 2 and 3):	DB package 70°C/W
	DW package 58°C/W
	N package 69°C/W
	PW package 83°C/W
Operating virtual junction temperature, T <sub>J</sub>	150°C
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to the network ground terminal.
  - 2. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
  - 3. The package thermal impedance is calculated in accordance with JESD 51-7.



## GD65232, GD75232 **MULTIPLÉ RS-232 DRIVERS AND RECEIVERS**

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#### recommended operating conditions

			MIN	NOM	MAX	UNIT
$V_{DD}$	Supply voltage (see Note 4)		7.5	9	15	V
VSS	Supply voltage (see Note 4)		-7.5	-9	-15	V
Vcc	Supply voltage (see Note 4)		4.5	5	5.5	V
VIH	High-level input voltage (driver only)		1.9			V
$V_{IL}$	Low-level input voltage (driver only)				0.8	V
la	High level cutout current	Driver			-6	A
IOH	High-level output current	Receiver			-0.5	mA
la.	Lour lovel or thout or throat	Driver			6	A
IOL	Low-level output current	Receiver			16	mA
т.	Operating free air temperature	GD65232	-40		85	°C
TA	Operating free-air temperature	GD75232	0		70	را

NOTE 4: When powering up the GD65232 and GD75232, the following sequence should be used:

- 1. V<sub>SS</sub>
- 2. V<sub>DD</sub> 3. V<sub>CC</sub> 4. I/Os

Applying  $V_{CC}$  before  $V_{DD}$  may allow large currents to flow, causing damage to the device. When powering down the GD65232 and GD75232, the reverse sequence should be used.

#### supply currents over recommended operating free-air temperature range

	PARAMETER		TEST CO	NDITIONS		MIN MAX	UNIT
				$V_{DD} = 9 V$ ,	$V_{SS} = -9 V$	15	
		All inputs at 1.9 V,	No load	$V_{DD} = 12 V$ ,	$V_{SS} = -12 \text{ V}$	19	
	Committee and the many 1/-			$V_{DD} = 15 V$ ,	$V_{SS} = -15 \text{ V}$	25	
IDD	Supply current from V <sub>DD</sub>			V <sub>DD</sub> = 9 V,	$V_{SS} = -9 V$	4.5	mA
		All inputs at 0.8 V,	No load	$V_{DD} = 12 V$ ,	$V_{SS} = -12 \text{ V}$	5.5	
				$V_{DD} = 15 V$ ,	$V_{SS} = -15 \text{ V}$	9	
				V <sub>DD</sub> = 9 V,	V <sub>SS</sub> = -9 V	-15	
		All inputs at 1.9 V,	No load	$V_{DD} = 12 V$ ,	$V_{SS} = -12 \text{ V}$	-19	
	Commission assume at the as Man			$V_{DD} = 15 V$ ,	$V_{SS} = -15 \text{ V}$	-25	
Iss	Supply current from V <sub>SS</sub>			V <sub>DD</sub> = 9 V,	V <sub>SS</sub> = -9 V	-3.2	mA
		All inputs at 0.8 V,	No load	$V_{DD} = 12 V$ ,	V <sub>SS</sub> = -12 V	-3.2	!
				$V_{DD} = 15 V$ ,	$V_{SS} = -15 \text{ V}$	-3.2	!
laa	Cumply ourrant from \/a a	All inputs at F.V	No load,	V22 - F.V	GD65232	38	mA
ICC	Supply current from V <sub>CC</sub>	All inputs at 5 V,	ino ioau,	V <sub>CC</sub> = 5 V	GD75232	30	IIIA

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#### **DRIVER SECTION**

## electrical characteristics over recommended operating free-air temperature range, $V_{DD}$ = 9 V, $V_{SS}$ = -9 V, $V_{CC}$ = 5 V (unless otherwise noted)

	PARAMETER		TEST CONDITION	ONS	MIN	TYP	MAX	UNIT
Vон	High-level output voltage	V <sub>IL</sub> = 0.8 V,	$R_L = 3 k\Omega$ ,	See Figure 1	6	7.5		V
VOL	Low-level output voltage (see Note 5)	V <sub>IH</sub> = 1.9 V,	$R_L = 3 \text{ k}\Omega$ ,	See Figure 1		-7.5	-6	V
I <sub>IH</sub>	High-level input current	V <sub>I</sub> = 5 V,	See Figure 2				10	μΑ
IIL	Low-level input current	$V_{I} = 0,$	See Figure 2				-1.6	mA
IOS(H)	High-level short-circuit output current (see Note 6)	V <sub>IL</sub> = 0.8 V,	V <sub>O</sub> = 0,	See Figure 1	-4.5	-12	-19.5	mA
IOS(L)	Low-level short-circuit output current	V <sub>IH</sub> = 2 V,	$V_{O} = 0$ ,	See Figure 1	4.5	12	19.5	mA
r <sub>O</sub>	Output resistance (see Note 7)	VCC = VDD =	$V_{SS} = 0$ ,	$V_O = -2 V \text{ to } 2 V$	300			Ω

- NOTES: 5. The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only (e.g., if –10 V is maximum, the typical value is a more negative voltage).
  - 6. Output short-circuit conditions must maintain the total power dissipation below absolute maximum ratings.
  - 7. Test conditions are those specified by TIA/EIA-232-F and as listed above.

## switching characteristics, $V_{CC}$ = 5 V, $V_{DD}$ = 12 V, $V_{SS}$ = -12 V, $T_A$ = 25°C

	PARAMETER		MIN	TYP	MAX	UNIT		
<sup>t</sup> PLH	Propagation delay time, low- to high-level output	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	C <sub>L</sub> = 15 pF,	See Figure 3		315	500	ns
tPHL	Propagation delay time, high- to low-level output	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	C <sub>L</sub> = 15 pF,	See Figure 3		75	175	ns
	Transition time,	D 0101-710	C <sub>L</sub> = 15 pF,	See Figure 3		60	100	ns
<sup>t</sup> TLH	low- to high-level output	$R_L = 3 k\Omega \text{ to } 7 k\Omega$	$C_L = 2500 \text{ pF},$	See Figure 3 and Note 8		1.7	2.5	μs
<b></b>	Transition time,	$R_1 = 3 k\Omega \text{ to } 7 k\Omega$	$C_L = 15 pF$ ,	See Figure 3		40	75	ns
tTHL	high- to low-level output	K[ = 3 K22 to 7 K22	C <sub>L</sub> = 2500 pF,	See Figure 3 and Note 8		1.5	2.5	μs

NOTE 8: Measured between ±3-V and ±3-V points of the output waveform (TIA/EIA-232-F conditions); all unused inputs are tied either high or low.



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#### **RECEIVER SECTION**

## electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TES	ST CONDITIONS		MIN	TYP†	MAX	UNIT
.,	B 10 1 1 1 1 1	T <sub>A</sub> = 25°C,	See Figure 5		1.75	1.9	2.3	.,
V <sub>IT+</sub>	Positive-going input threshold voltage	$T_A = 0$ °C to $70$ °C,	See Figure 5		1.55		2.3	V
V <sub>IT</sub> _	Negative-going input threshold voltage				0.75	0.97	1.25	V
V <sub>hys</sub>	Input hysteresis voltage (V <sub>IT+</sub> - V <sub>IT-</sub> )				0.5			V
.,			V <sub>IH</sub> = 0.75 V		2.6	4	5	
VOH	High-level output voltage	$I_{OH} = -0.5 \text{ mA}$	Inputs open		2.6			V
VOL	Low-level output voltage	I <sub>OL</sub> = 10 mA,	V <sub>I</sub> = 3 V			0.2	0.45	V
		V 05.V	0 5 5	GD65232	3.6		11	
ΙΗ	High-level input current	$V_{I} = 25 V,$	See Figure 5	GD75232	3.6		8.3	mA
		V <sub>I</sub> = 3 V,	See Figure 5		0.43			
		.,		GD65232	-3.6		-11	
I <sub>IL</sub>	Low-level input current	$V_{I} = -25 \text{ V},$	See Figure 5	GD75232	-3.6		-8.3	mA
		$V_{I} = -3 V$ ,	See Figure 5		-0.43			
los	Short-circuit output current	See Figure 4				-3.4	-12	mA

<sup>†</sup> All typical values are at  $T_A = 25^{\circ}C$ ,  $V_{CC} = 5$  V,  $V_{DD} = 9$  V, and  $V_{SS} = -9$  V.

## switching characteristics, $V_{CC}$ = 5 V, $V_{DD}$ = 12 V, $V_{SS}$ = -12 V, $T_A$ = 25°C

	PARAMETER	T	EST CONDITIO	MIN	TYP	MAX	UNIT	
t <sub>PLH</sub>	Propagation delay time, low- to high-level output					107	250	ns
tPHL	Propagation delay time, high- to low-level output	C 50 pE	D 5 kO	Soo Figuro 6		42	150	ns
tTLH	Transition time, low- to high-level output	$C_L = 50 pF$ ,	$R_L = 5 k\Omega$ ,	See Figure 6		175	350	ns
tTHL	Transition time, high- to low-level output					16	60	ns
tPLH	Propagation delay time, low- to high-level output					100	160	ns
tPHL	Propagation delay time, high- to low-level output	C. 45 nF	D: 4.5 kO	Coo Figure 6		60	100	ns
tTLH	Transition time, low- to high-level output	CL = 15 pr,	$R_L = 1.5 \text{ k}\Omega$ ,	See rigure 6		90	175	ns
tTHL	Transition time, high- to low-level output					15	50	ns



#### PARAMETER MEASUREMENT INFORMATION

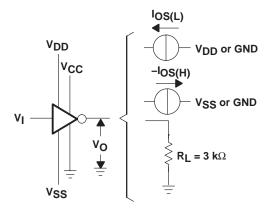


Figure 1. Driver Test Circuit for  $V_{OH}$ ,  $V_{OL}$ ,  $I_{OS(H)}$ , and  $I_{OS(L)}$ 

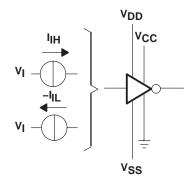
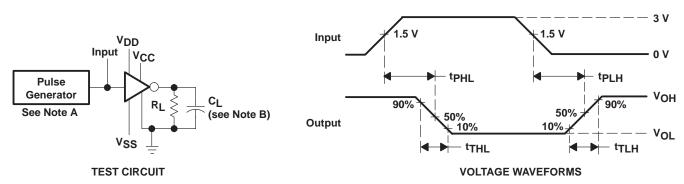


Figure 2. Driver Test Circuit for IIH and IIL



NOTES: A. The pulse generator has the following characteristics:  $t_W = 25 \mu s$ , PRR = 20 kHz,  $Z_O = 50 \Omega$ ,  $t_T = t_f < 50 ns$ .

B. C<sub>L</sub> includes probe and jig capacitance.

Figure 3. Driver Test Circuit and Voltage Waveforms

#### PARAMETER MEASUREMENT INFORMATION

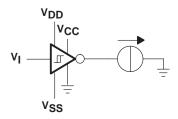


Figure 4. Receiver Test Circuit for IOS

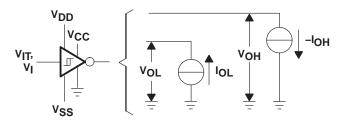
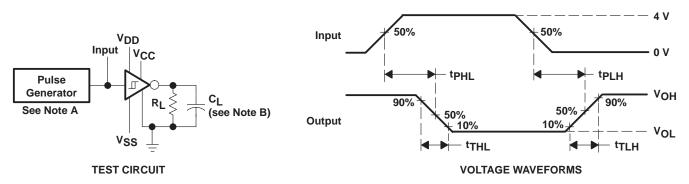


Figure 5. Receiver Test Circuit for VIT, VOH, and VOL

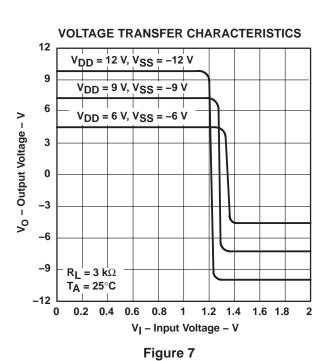


NOTES: A. The pulse generator has the following characteristics:  $t_W$  = 25  $\mu$ s, PRR = 20 kHz,  $Z_O$  = 50  $\Omega$ ,  $t_f$  =  $t_f$  < 50 ns.

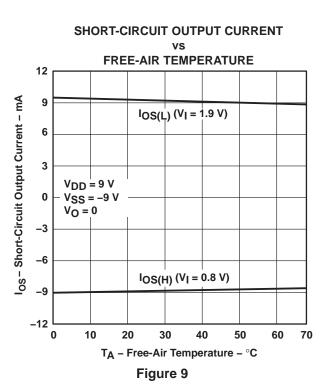
B. C<sub>L</sub> includes probe and jig capacitance.

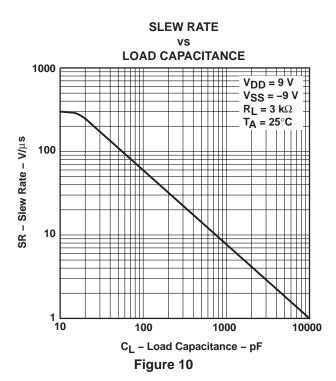
Figure 6. Receiver Propagation and Transition Times

# TYPICAL CHARACTERISTICS DRIVER SECTION

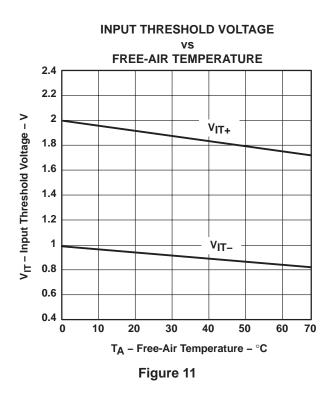


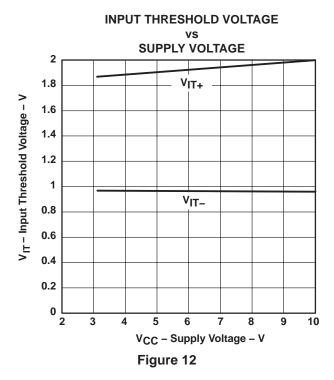
**OUTPUT CURRENT OUTPUT VOLTAGE** 20  $V_{DD} = 9 V$ 16  $V_{SS} = -9 V$  $T_A = 25^{\circ}C$  $V_{OL} (V_{I} = 1.9 V)$ 12 Io - Output Current - mA 8 4 0 -8  $3-k\Omega$ **Load Line** -12  $V_{OH} (V_I = 0.8^{\dagger} V)$ -16 -20 -12 -8 12 16 -16 VO - Output Voltage - V Figure 8

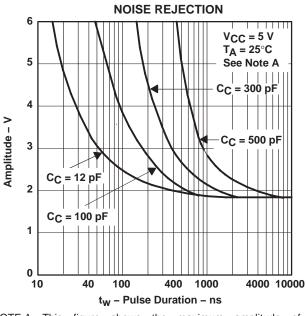




#### TYPICAL CHARACTERISTICS







NOTE A: This figure shows the maximum amplitude of a positive-going pulse that, starting from 0 V, does not cause a change of the output level.

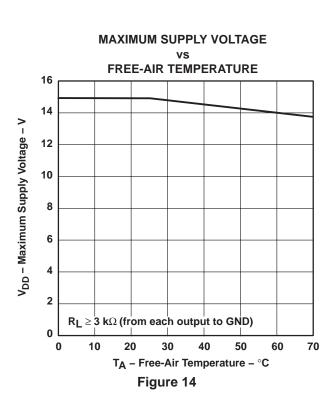


Figure 13

#### **APPLICATION INFORMATION**

Diodes placed in series with the  $V_{DD}$  and  $V_{SS}$  leads protect the GD65232 and GD75232 in the fault condition in which the device outputs are shorted to  $\pm 15$  V and the power supplies are at low and provide low-impedance paths to ground (see Figure 15).

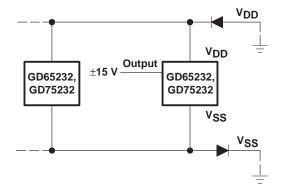


Figure 15. Power-Supply Protection to Meet Power-Off Fault Conditions of TIA/EIA-232-F

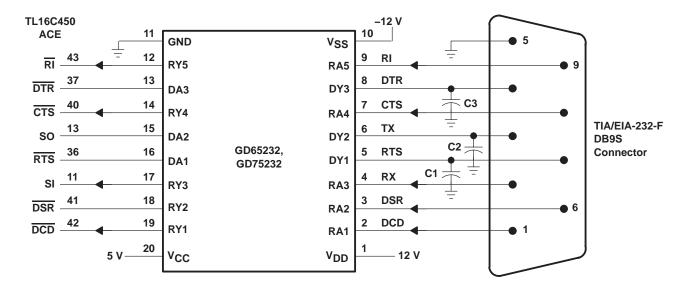


Figure 16. Typical Connection

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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
GD65232DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GD65232	Samples
GD65232DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GD65232	Samples
GD65232PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	GD65232	Samples
GD75232DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75232	Samples
GD75232DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75232	Samples
GD75232DWE4	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75232	Samples
GD75232DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75232	Samples
GD75232DWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75232	Samples
GD75232N	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	0 to 70	GD75232N	Samples
GD75232PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75232	Samples
GD75232PWE4	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75232	Samples
GD75232PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	0 to 70	GD75232	Samples
GD75232PWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75232	Samples

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



## PACKAGE OPTION ADDENDUM

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**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**PACKAGE MATERIALS INFORMATION** 

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#### TAPE AND REEL INFORMATION





	Α0	Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ı	P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
GD65232DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
GD65232PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
GD75232DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
GD75232DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
GD75232PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
GD75232PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
GD75232PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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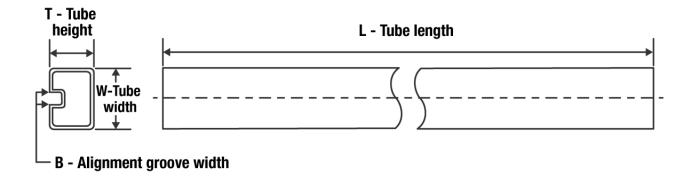


\*All dimensions are nominal

Davida	Deeless Tons	Dardina Dardina	D:	000	Lawrett (mass)	MC Idly (many)	Halada (mana)
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
GD65232DWR	SOIC	DW	20	2000	367.0	367.0	45.0
GD65232PWR	TSSOP	PW	20	2000	853.0	449.0	35.0
GD75232DBR	SSOP	DB	20	2000	853.0	449.0	35.0
GD75232DWR	SOIC	DW	20	2000	367.0	367.0	45.0
GD75232PWR	TSSOP	PW	20	2000	364.0	364.0	27.0
GD75232PWR	TSSOP	PW	20	2000	853.0	449.0	35.0
GD75232PWRG4	TSSOP	PW	20	2000	853.0	449.0	35.0

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#### **TUBE**



\*All dimensions are nominal

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Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
GD65232DW	DW	SOIC	20	25	507	12.83	5080	6.6
GD75232DW	DW	SOIC	20	25	507	12.83	5080	6.6
GD75232DW	DW	SOIC	20	25	506.98	12.7	4826	6.6
GD75232DWE4	DW	SOIC	20	25	507	12.83	5080	6.6
GD75232DWE4	DW	SOIC	20	25	506.98	12.7	4826	6.6
GD75232N	N	PDIP	20	20	506	13.97	11230	4.32
GD75232PW	PW	TSSOP	20	70	530	10.2	3600	3.5
GD75232PWE4	PW	TSSOP	20	70	530	10.2	3600	3.5





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## PW (R-PDSO-G20)

## PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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